

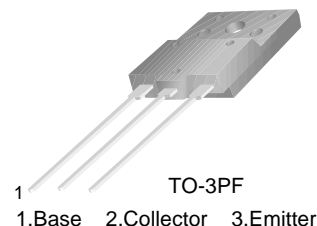
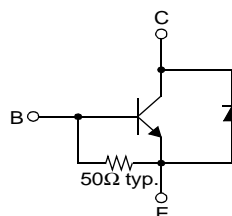
# KSC5802D

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## High Voltage Color Display Horizontal Deflection Output (Built In Damper Diode)

- High Breakdown Voltage  $BV_{CBO}=1500V$
- High Speed Switching :  $t_F=0.1\mu s$  (Typ.)
- Wide S.O.A
- For C-Monitor(69KHz)

Equivalent Circuit



## NPN Triple Diffused Planar Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

| Symbol    | Parameter                                  | Value      | Units      |
|-----------|--|------------|------------|
| $V_{CBO}$ | Collector-Base Voltage                     | 1500       | V          |
| $V_{CEO}$ | Collector-Emitter Voltage                  | 800        | V          |
| $V_{EBO}$ | Emitter-Base Voltage                       | 6          | V          |
| $I_C$     | Collector Current (DC)                     | 10         | A          |
| $I_{CP}$  | Collector Current (Pulse)                  | 30         | A          |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ C$ ) | 60         | W          |
| $T_J$     | Junction Temperature                       | 150        | $^\circ C$ |
| $T_{STG}$ | Storage Temperature                        | - 55 ~ 150 | $^\circ C$ |

### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

| Symbol                 | Parameter                            | Test Condition  | Min.    | Typ. | Max.       | Units   |
|------------------------|--------------------------------------|---|---------|------|------------|---------|
| $I_{CES}$              | Collector Cut-off Current            | $V_{CE} = 1400V, V_{BE}=0$  |         |      | 1          | mA      |
| $I_{CBO}$              | Collector Cut-off Current            | $V_{CB} = 800V, I_E = 0$  |         |      | 10         | $\mu A$ |
| $I_{EBO}$              | Emitter Cut-off Current              | $V_{EB} = 4V, I_C = 0$  | 50      |      | 250        | mA      |
| $h_{FE1}$<br>$h_{FE2}$ | DC Current Gain                      | $V_{CE} = 5V, I_C = 1A$<br>$V_{CE} = 5V, I_C = 6A$                                  | 15<br>7 |      | 40<br>11.5 |         |
| $V_{CE(sat)}$          | Collector-Emitter Saturation Voltage | $I_C = 6A, I_B = 1.5A$  |         |      | 3          | V       |
| $V_{BE(sat)}$          | Base-Emitter Saturation Voltage      | $I_C = 6A, I_B = 1.5A$  |         |      | 1.5        | V       |
| $t_F$                  | Fall Time                            | $V_{CC} = 200V, I_C = 6A$<br>$I_{B1} = 1.2A, I_{B2} = - 2.4A$<br>$R_L = 33.3\Omega$ |         | 0.1  | 0.3        | $\mu s$ |

# Typical Characteristics

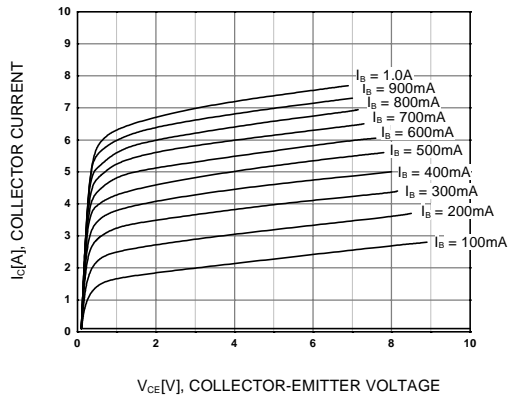


Figure 1. Static Characteristic

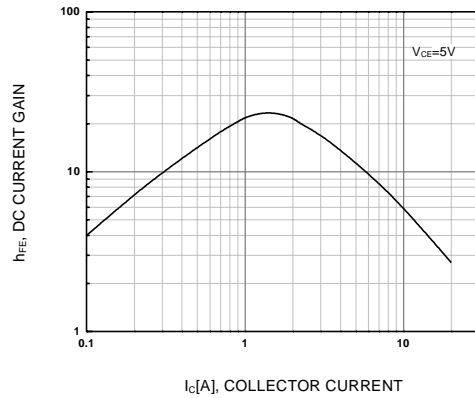


Figure 2. DC current Gain

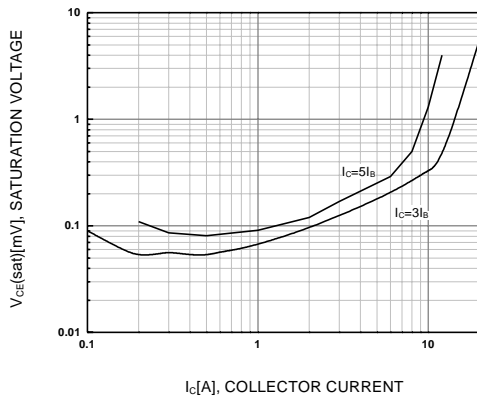


Figure 3. Collector-Emitter Saturation Voltage

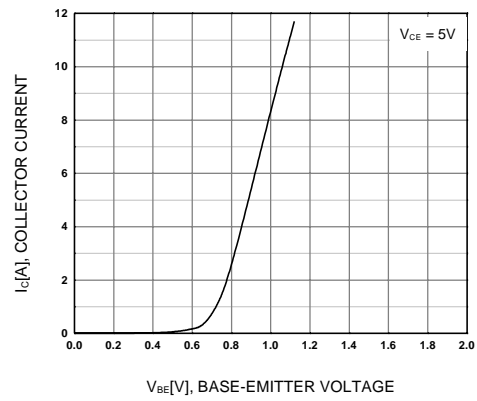


Figure 4. Base-Emitter On Voltage

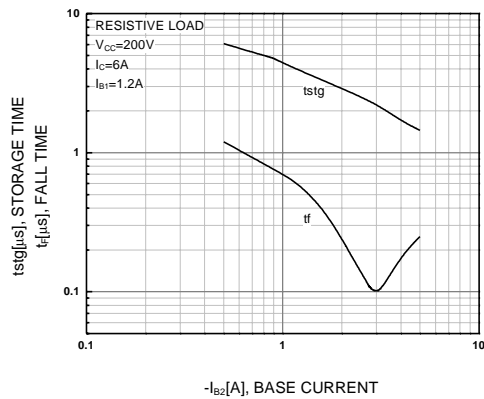


Figure 5. Switching Time

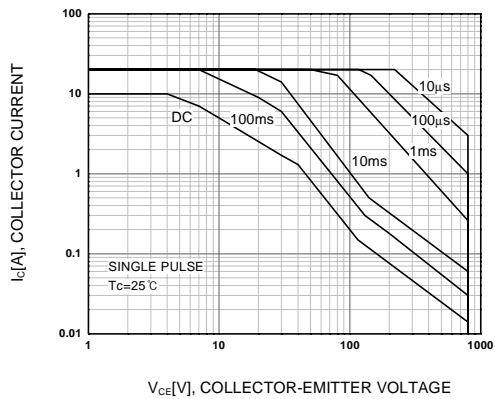


Figure 6. Safe Operating Area

# Typical Characteristics (Continued)

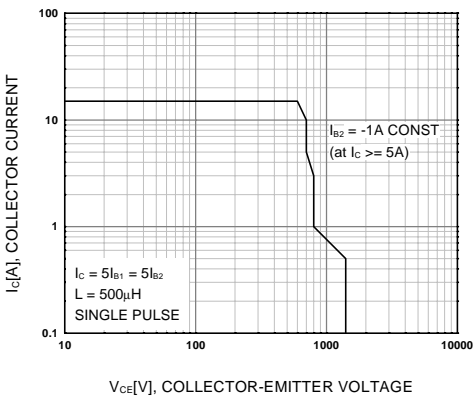


Figure 7. Reverse Bias Safe Operating Area

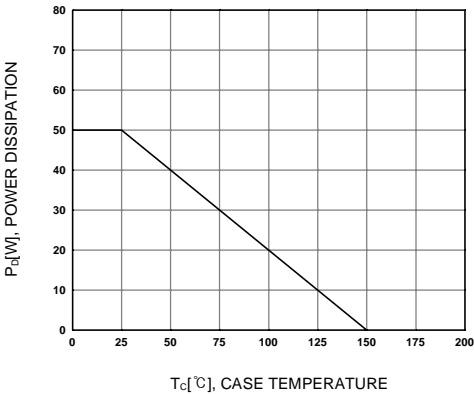
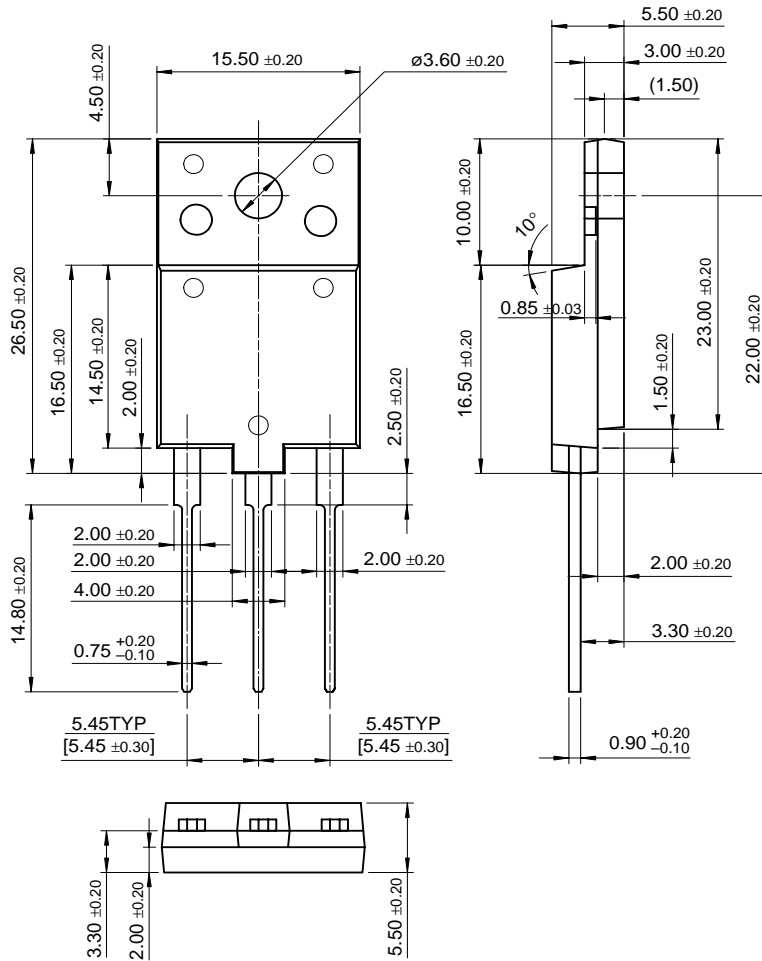


Figure 8. Power Derating

# Package Dimensions

## TO-3PF



Dimensions in Millimeters

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